- Rugged Triple-Diffused Planar Construction
- 4 A Continuous Collector Current
- Operating Characteristics Fully Guaranteed at 100°C
- 1000 Volt Blocking Capability

Pin 2 is in electrical contact with the mounting base.

MDTRACA

absolute maximum ratings at 25°C case temperature (unless otherwise noted)

RATING	SYMBOL	VALUE	UNIT
Collector-base voltage (I _E = 0)	V _{CBO}	850 1000	V
Collector-emitter voltage (V _{BE} = 0)	V _{CES}	850 1000	V
Collector-emitter voltage (I _B = 0)	V _{CEO}	400 450	٧
Emitter-base voltage	V _{EBO}	10	V
Continuous collector current	I _C	4	Α
Peak collector current (see Note 1)	I _{CM}	8	Α
Continuous device dissipation at (or below) 25°C case temperature	P _{tot}	75	W
Operating junction temperature range	T _j	-65 to +150	°C
Storage temperature range	T _{stg}	-65 to +150	°C

NOTE 1: This value applies for $t_p \le 10$ ms, duty cycle $\le 2\%$.



TIPL791, TIPL791A NPN SILICON POWER TRANSISTORS

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electrical characteristics at 25°C case temperature (unless otherwise noted)

1	TEST CONDITIONS					MIN	TYP	MAX	UNIT	
V _{CEO(sus)}	Collector-emitter sustaining voltage	I _C = 10	00 mA	L = 25 mH	(see Note 2)	TIPL791 TIPL791A	400 450			V
		V _{CE} =	850 V	V _{BE} = 0		TIPL791			5	
	Collector-emitter	V _{CE} = 1	000 V	$V_{BE} = 0$		TIPL791A			5	μΑ
I _{CES}	cut-off current	V _{CE} =	850 V	$V_{BE} = 0$	$T_C = 100$ °C	TIPL791			200	μΑ
		V _{CE} = 1	000 V	$V_{BE} = 0$	$T_C = 100$ °C	TIPL791A			200	
lana	Collector cut-off	V _{CE} =	400 V	$I_B = 0$		TIPL791			5	μA
I _{CEO}	current	V _{CE} =	450 V	$I_B = 0$		TIPL791A			5	μΛ
I _{EBO}	Emitter cut-off current	V _{EB} =	10 V	I _C = 0					1	mA
h _{FE}	Forward current transfer ratio	V _{CE} =	5 V	I _C = 0.5 A	(see Notes 3 ar	nd 4)	20		60	
		I _B =	0.2 A	I _C = 1 A	(see Notes 3 and 4)				0.5	
V _{CE(sat)}	Collector-emitter	I _B =	0.5 A	$I_C = 2.5 A$					1.0	V
* CE(Sai)	saturation voltage	I _B =	1 A	$I_C = 4 A$					2.5	·
		I _B =	1 A	$I_C = 4 A$	$T_C = 100^{\circ}C$				5.0	
		I _B =	0.2 A	I _C = 1 A					1.0	
V _{BE(sat)}	Base-emitter	I _B =	0.5 A	$I_{\rm C} = 2.5 {\rm A}$	(see Notes 3 ar	nd 4)			1.2	V
	saturation voltage	I _B =	1 A	$I_C = 4 A$					1.4	
		I _B =	1 A	$I_C = 4 A$	$T_C = 100$ °C				1.3	
f _t	Current gain bandwidth product	V _{CE} =	10 V	$I_{\rm C} = 0.5 {\rm A}$	f = 1 MHz			12		MHz
C _{ob}	Output capacitance	V _{CB} =	20 V	I _E = 0	f = 0.1 MHz			110		pF

NOTES: 2. Inductive loop switching measurement.

- 3. These parameters must be measured using pulse techniques, t_p = 300 μs , duty cycle \leq 2%.
- 4. These parameters must be measured using voltage-sensing contacts, separate from the current carrying contacts.

thermal characteristics

PARAMETER			TYP	MAX	UNIT
$R_{\theta JC}$	Junction to case thermal resistance			1.66	°C/W

inductive-load-switching characteristics at 25°C case temperature (unless otherwise noted)

	PARAMETER	TEST CONDITIONS †			MIN	TYP	MAX	UNIT
t _{sv}	Voltage storage time	I _C = 4 A V _{BE(off)} = -5 V	I _{B(on)} = 0.8A	(see Figures 1 and 2)			2	μs
t _{rv}	Voltage rise time						200	ns
t _{fi}	Current fall time						100	ns
t _{ti}	Current tail time						50	ns
t _{xo}	Cross over time						200	ns
t _{sv}	Voltage storage time	I _C = 4 A V _{BE(off)} = -5 V	$I_{B(on)} = 0.8A$ $T_{C} = 100^{\circ}C$				2.5	μs
t _{rv}	Voltage rise time			(see Figures 1 and 2)			400	ns
t _{fi}	Current fall time						200	ns
t _{ti}	Current tail time						50	ns
t _{xo}	Cross over time						600	ns

[†] Voltage and current values shown are nominal; exact values vary slightly with transistor parameters.

PARAMETER MEASUREMENT INFORMATION

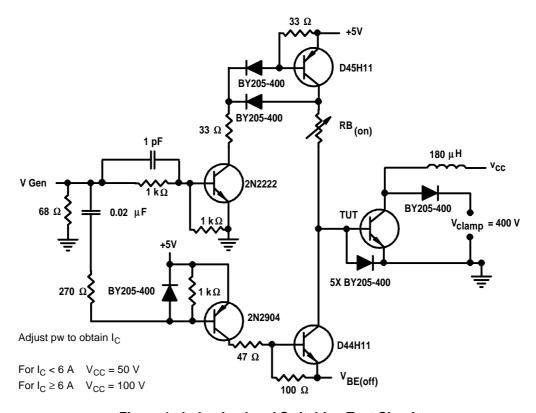
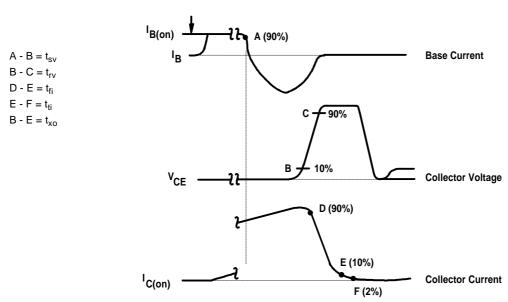


Figure 1. Inductive-Load Switching Test Circuit

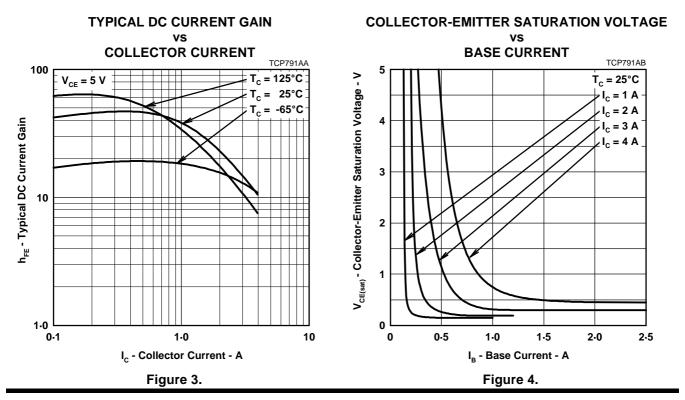


NOTES: A. Waveforms are monitored on an oscilloscope with the following characteristics: $t_r < 15$ ns, $R_{in} > 10 \Omega$, $C_{in} < 11.5$ pF. B. Resistors must be noninductive types.

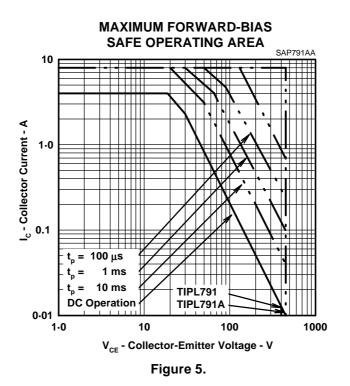
Figure 2. Inductive-Load Switching Waveforms



TYPICAL CHARACTERISTICS



MAXIMUM SAFE OPERATING REGIONS



THERMAL INFORMATION

THERMAL RESPONSE JUNCTION TO CASE

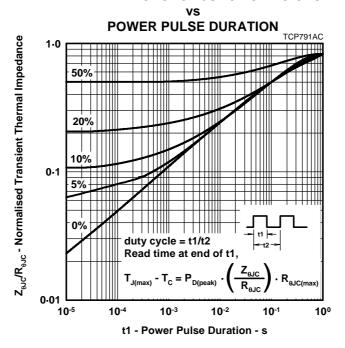


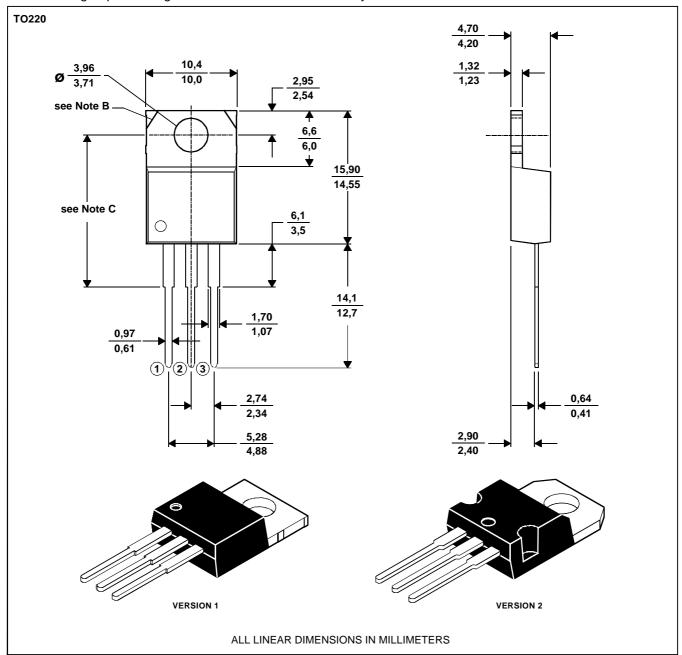
Figure 6.

MECHANICAL DATA

TO-220

3-pin plastic flange-mount package

This single-in-line package consists of a circuit mounted on a lead frame and encapsulated within a plastic compound. The compound will withstand soldering temperature with no deformation, and circuit performance characteristics will remain stable when operated in high humidity conditions. Leads require no additional cleaning or processing when used in soldered assembly.



NOTES: A. The centre pin is in electrical contact with the mounting tab.

- B. Mounting tab corner profile according to package version.
- C. Typical fixing hole centre stand off height according to package version. Version 1, 18.0 mm. Version 2, 17.6 mm.

MDXXBE

PRODUCT INFORMATION

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